Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1713	257/355.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/10 10:19
S1	0	electro$static adj discharge same scr same asymetric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 17:08
S2	431	electro$static adj discharge same scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 17:14
S3	901	(esd electro$static adj discharge) same (scr silicon adj controlled adj rectifier)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 10:12
S4	3	(esd electro$static adj discharge) same (scr silicon adj controlled adj rectifier) same asymmetric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 17:16
S5	8	(esd electro$static adj discharge) same (scr silicon adj controlled adj rectifier) and asymmetric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 17:16
S6	22	scr and wu.in. and (taiwan adj semiconductor).as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 17:22
S7	16	(esd electro$static adj discharge) same (scr silicon adj controlled adj rectifier) same (NFET NMOS) same (PFET PMOS) same buffer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 10:57

S8	32	("4734752" | "5019888" | "5218222" | "5270565" | "5329143" | "5600525").PN. OR ("5754381"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/06 10:24
S9	19	("5528188" | "5530612" | "5572394" | "5740000" | "5754381" | "5886862" | "5907464" | "5917336" | "5945713" | "5959820" | "6002568" | "6008684" | "6011681" | "6043539").PN. OR ("6671153").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/06 10:30
S10	7	("5754381" | "5856214" | "5872379" | "5907462" | "5939756" | "5959820").PN. OR ("6576934"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/06 10:48
S11	21	("5400202" | "5465189" | "5576557" | "5745323" | "5754380" | "5754381" | "5869873" | "5898205").PN. OR ("6066879"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/06 10:51
S12	28	(esd electro$static adj discharge) same (scr silicon adj controlled adj rectifier) same (NFET NMOS) same (PFET PMOS) and diode near (chain string)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 11:06
S13	9	10/099600	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 11:06
S14	35	("5272097" | "5272371" | "5327319" | "5400202" | "5426322" | "5430595" | "5452171" | "5465189" | "5550699" | "5561577" | "5591661" | "5610425" | "5625522" | "5671111" | "5728612" | "5754380" | "5780905" | "5781388" | "5821572" | "5843813" | "5869873" | "5872378" | "5877927" | "5907462" | "5959488" | "5959821" | "5978192" | "5982601" | "6002567" | "6069782" | "6125021" | "6157530" | "6233130" | "6304127" | "6411485").PN. OR ("6768616"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/06 11:11
S15	10	("5311391").PN. OR ("5550699"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/06 11:25

S16	38	("4922371" | "5225702" | "5274262" | "5287241").PN. OR ("5430595").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/06 14:41
S17	1	10/812378	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/06 14:41
S18	59	asymmetric near (nmos nfet pmos pfet fet)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 15:31
S19	1	asymmetric near (nmos nfet pmos pfet fet) and (scr silicon adj controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 15:14
S20	305	asymmetric near (nmos nfet pmos pfet fet transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/06 15:15
S21	2	asymmetric near (nmos nfet pmos pfet fet transistor) and (scr silicon adj controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/06 15:16
S22	18	"5905288"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 15:31
S23	0	"5905288.pn."	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 15:32
S24	2	"5905288".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 15:45

S25	2	"6768616".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 15:45
S26	35	("5272097" | "5272371" | "5327319" | "5400202" | "5426322" | "5430595" | "5452171" | "5465189" | "5550699" | "5561577" | "5591661" | "5610425" | "5625522" | "5671111" | "5728612" | "5754380" | "5780905" | "5781388" | "5821572" | "5843813" | "5869873" | "5872378" | "5877927" | "5907462" | "5959488" | "5959821" | "5978192" | "5982601" | "6002567" | "6069782" | "6125021" | "6157530" | "6233130" | "6304127" | "6411485").PN. OR ("6768616"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/06 15:49
S27	13	mergens.in. and sarnoff.as.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/06 15:50
S28	17	diode adj (string chain) same bias same scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:13
S29	1133910	lateral scr.ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 16:57
S30	14	(lateral adj scr).ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 16:57
S31	17	diode adj (string chain) same bias same nmos	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:13

S32	18	diode adj (string chain) same bias same (nmos nfet)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:19
S33	9	diode adj (string chain) same bias same (mos fet)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:20
S34	12	("3501591" | "3886321" | "3927266" | "3953682" | "4099032" | "4158752" | "4360709").PN. OR ("4439634").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/06 17:20
S35	837	diode adj (string chain) and (scr silicon controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:20
S36	32	diode adj (string chain) same $1fet and (scr silicon controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:21
S37	3972858	diode adj (string chain) same sourceand (scr silicon controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:21
S38	256	diode adj (string chain) same source and (scr silicon controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:21
S39	72	diode adj (string chain) same source same (scr silicon controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:25
S40	61392	diode adj (string chain) same source (scr silicon adj controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:25

S41	17	diode adj (string chain) same source same (scr silicon adj controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:28
S42	378	diode adj (string chain) same source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:36
S43	1	"6768616".pn. and holding same chain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/07 10:03
S44	12	source same holding same diode adj (chain string)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 17:52
S45	14	("3335360" | "3506852" | "3577177" | "3848140" | "3917962").PN. OR ("4024457"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/06 17:49
S46	42	holding adj voltage and diode adj (chain string) and (scr silicon adj controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 18:08
S47	44	holding adj voltage and diode adj (chain string stack) and (scr silicon adj controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/06 18:08
S48	284	holding adj voltage and scr and diode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:03
S49	105	holding adj voltage same scr same diode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:11

S50	37	holding adj voltage same scr same diode same latch$1up	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:16
S51	408	output adj buffer and diode adj (chain string stack series)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:17
S52	13	output adj buffer and diode adj (chain string stack series) and scr and holding adj voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:22
S53	21	buffer and diode adj (chain string stack series) and scr and holding adj voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:26
S54	177	buffer same diode adj (chain string stack series)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:26
S55	10	buffer same diode adj (chain string stack series) and (scr and silicon adj controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:31
S56	2180	(WU LEE).IN. AND (taiwan adj semiconductor).as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:32
S57	86	(WU LEE).IN. AND (taiwan adj semiconductor).as. and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/08 15:23

S58	18	(WU LEE).IN. AND (taiwan adj semiconductor).as. and diode adj (chain string series stack)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:33
S59	2336	diode adj (chain sereies stack string) (taiwan adj semiconductor). as. and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:41
S60	17	diode adj (chain sereies stack string) and (taiwan adj semiconductor).as. and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:47
S61	84	diode adj (chain sereies stack string) and latch$1up and esd	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:47
S62	41	diode adj (chain sereies stack string) and latch$1up and esd and holding	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 16:39
S63	6	10/099263	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 10:58
S64	68	buffer same diode adj (chain string stack series) same source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 16:46
S65	2	"6768616".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 11:08

S66	0	sarnoff.in. and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 11:09
S67	54	sarnoff.as. and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 11:09
S68	40	("4392781" | "4400711" | "4405933" | "4484244" | "4631567" | "4633283" | "4757363" | "4760433" | "4811155" | "4855620" | "4870530" | "4928157").PN. OR ("5010380").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 11:12
S69	18	("3806773" | "4476476" | "4686602" | "4763184" | "4870530" | "4937471" | "5010380" | "5060037" | "5343053" | "5349212" | "5465189" | "5548134" | "5610426" | "5780905" | "5814865" | "5895940" | "6013941" | "6064093").PN. OR ("6825504"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 11:13
S70	14	("4870530" | "5400202" | "5602404").PN. OR ("5780905"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 11:15
S71	18	("3806773" | "4476476" | "4686602" | "4763184" | "4870530" | "4937471" | "5010380" | "5060037" | "5343053" | "5349212" | "5465189" | "5548134" | "5610426" | "5780905" | "5814865" | "5895940" | "6013941" | "6064093").PN. OR ("6825504"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 11:17
S72	13	("4071779" | "4302792" | "4439802" | "4484244" | "4567500").PN. OR ("4686602"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 11:20
S73	18	("3806773" | "4476476" | "4686602" | "4763184" | "4870530" | "4937471" | "5010380" | "5060037" | "5343053" | "5349212" | "5465189" | "5548134" | "5610426" | "5780905" | "5814865" | "5895940" | "6013941" | "6064093").PN. OR ("6825504"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 15:39

S74	1	"4825174".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 15:41
S75	120	(silicon adj controlled) and buffer same source same diode	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 15:42
S76	18	(silicon adj controlled) and buffer same source same diode same holding	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 15:43
S77	18	(silicon adj controlled) and buffer same source same diode$1 same holding	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 15:43
S78	18	(silicon adj controlled) and buffer same (source drain) same diode$1 same holding	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 15:45
S79	32	(silicon adj controlled) and buffer same diode$1 same holding	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 15:48
S80	50	(silicon adj controlled) and (nmos nfet) with diode$1 and holding	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 15:56
S81	15	Chartered.as. and scr	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 15:58
S82	37	Chartered.as. and esd	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 15:58
S83	15	("4037164" | "5528190" | "5576557" | "5631793" | "5895940" | "5905288" | "5986862" | "6008974" | "6130811").PN. OR ("6275089").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 16:04
S84	19	("5077591" | "5225702" | "5274262" | "5453384" | "5465189" | "5473169" | "5485024" | "5493133" | "5500546" | "5506742").PN. OR ("5821572"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 16:37
S85	124	diode adj (chain series stack string) and latch$1up and esd and holding	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 16:39
S86	12	diode adj (chain series stack string) with holding and latch$1up and esd	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 16:44

S87	13	("5959820" | "6015992").PN. OR ("6521952").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 16:42
S88	0	diode adj (chain series stack string) with holding same latch$1up same buffer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 16:45
S89	1	diode adj (chain series stack string) same holding same latch$1up same buffer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 16:45
S90	3	diode adj (chain series stack string) same buffer and holding same latch$1up	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 16:45
S91	1	buffer same diode adj (chain string stack series) same (latch$1up latch adj up)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 16:47
S92	10	buffer same diode adj (chain string stack series) and (latch$1up latch adj up)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 17:02
S93	21	thick adj field adj oxide adj device	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 17:08
S94	2492	($1mos $1fet) with source with drain with gate with diode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 17:09
S95	73	($1mos $1fet) with source with drain with gate with diode same buffer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 17:09

S96	0	($1mos $1fet) with source with drain with gate with diode same buffer same holding	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 17:09
S97	0	($1mos $1fet) with source with drain with gate with diode same buffer same scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 17:09
S98	0	($1mos $1fet) with source with drain with gate with diode same buffer same $3scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 17:09
S99	73	($1mos $1fet) with source with drain with gate with diode same buffer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 17:10
S10 0	0	($1mos $1fet) with source with drain with gate with diode same buffer and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 17:10
S10 1	4	($1mos $1fet) with source with drain with gate with diode same buffer and esd	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 17:13
S10 2	2	"4767946".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/07 17:13
S10 3	17	("4456838" | "4578602" | "4644194").PN. OR ("4767946"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 17:16
S10 4	9	("4612514" | "4616189" | "4634993" | "4646028" | "4767946").PN. OR ("4825174"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 17:23
S10 5	36	buffer with diode adj (chain series string stack)	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 17:40

S106	990	hold$3 same (silicon adj controlled) same (chain string series stack)	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 17:47
S107	20	hold$3 same (silicon adj controlled) same diode adj (chain string series stack)	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 17:42
S108	8	hold$3 same (silicon adj controlled) same (chain string series stack) and nmos	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 17:54
S109	1	"4825174".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/07 17:54
S110	320	scr and esd and latch$1up	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 11:10
S111	99	scr same holding same latch$1up	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 11:32
S112	2	10/062714	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 11:32
S113	30	("20020084490" | "20030007301" | "4939616" | "5012317" | "5225702" | "5453384" | "5465189" | "5502328" | "5519242" | "5581104" | "5629544" | "5631793" | "5646808" | "5654862" | "5719737" | "5754381" | "5807791" | "5811857" | "5824573" | "5907462" | "5910874" | "5932918" | "5940258" | "5990520" | "6015992" | "6034397" | "6081002" | "6242763" | "6521952").PN. OR ("6750515").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/08 11:32
S114	1	10/812378	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 12:26

S11 5	2	"5905288".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 12:27
S11 6	2	"6521952".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 12:41
S11 7	273	snap$1back and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 12:42
S11 8	91	snap$1back and scr and speed	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 12:42
S11 9	2	snap$1back same speed same scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 12:42
S12 0	4	(taiwan adj semiconductor).as. and scr same speed	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 13:53
S12 1	2	beta adj gain with capacitance	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 13:54
S12 2	5	beta adj gain with scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 13:57

S123	11	beta adj gain same scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 13:59
S124	356	beta same scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 13:59
S125	4	beta same scr same capacitance	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 14:00
S126	32	beta same scr same increase	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 14:38
S127	137	asymmetric$3 near transistors	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 14:39
S128	1	asymmetric$3 near transistors and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 14:39
S129	137	asymmetric$3 near transistors	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 14:39
S130	0	asymmetric$3 near transistors and ker .in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 14:40

S13 1	0	asymmetric$3 near transistors and ker.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 14:40
S13 2	5	asymmetric$3 near transistors and esd	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 14:40
S13 3	95	ker.in. and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/08 15:06
S13 4	201	scr and guard adj ring	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/08 15:34
S13 5	1156	asymmetric with transistors	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/08 15:39
S13 6	11	asymmetric with transistors and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/08 15:49
S13 7	72	short adj channel adj NMOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/08 15:51
S13 8	23	short adj channel adj NMOS and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/08 15:52

S13 9	1	asymmetric$3 adj (NMOS NFET transistor$1)and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/08 15:54
S14 0	1	asymmetric$3 adj (NMOS NFET transistor$1) and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/08 15:54
S14 1	1	asymm$6 adj (NMOS NFET transistor$1) and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/08 15:54
S14 2	76	asymm$6 same (NMOS NFET transistor$1) and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/08 16:03
S14 3	6	asymm$6 with (source and drain) and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/08 16:04
S14 4	11	("20020058373" | "20030034527" | "4939616" | "5012317" | "5369041" | "5465189" | "5907462" | "6081002" | "6303420" | "6548337" | "6639284").PN. OR ("6869840"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/08 16:29
S14 5	4	257/592.ccls. and scr	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/08 16:29
S14 6	6	(257/592 257/593).ccls. and scr	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/08 16:35
S14 7	805	snap$1back and esd	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/08 16:36
S14 8	311	snap$1back and esd and buffer	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/08 16:36

S14 9	1	10/812378	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 11:18
S15 0	582	dual with asymm$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 11:18
S15 1	24	dual with asymm$5 same ($1fet $1mos transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 11:22
S15 2	342	(two dual) with asymm$5 same ($1fet $1mos transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 11:23
S15 3	2	(two dual) with asymm$5 same ($1fet $1mos transistor) same (silicon adj controlled scr)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 11:23
S15 4	4	(two dual) with asymm$5 same ($1fet $1mos transistor) and (silicon adj controlled scr)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 11:24
S15 5	27	(two dual) same asymm$5 same ($1fet $1mos transistor) and (silicon adj controlled scr)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 11:26
S15 6	1	(two dual double) near asymm$5 same ($1fet $1mos transistor) and (silicon adj controlled scr)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 11:26

S15 7	12	(two dual double) near asymm$5 and (silicon adj controlled scr)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR		OFF	2006/02/09 11:26
S15 8	101	(two dual double) with asymm$5 and (silicon adj controlled scr)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR		OFF	2006/02/09 11:27
S15 9	28	(two dual double) with asymm$5 and (silicon adj controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR		OFF	2006/02/09 11:28
S16 0	215	asymm$5 and (silicon adj controlled)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR		OFF	2006/02/09 11:28
S16 1	14	asymm$5 and (silicon adj controlled) and esd	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR		OFF	2006/02/09 11:28
S16 2	325	drain adj extended	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR		OFF	2006/02/09 12:08
S16 3	16	drain adj extended same scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR		OFF	2006/02/09 12:12
S16 4	2	"5,903,032".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR		OFF	2006/02/09 12:15

S16 5	41	denmos	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 12:15
S16 6	15	(denmos depmos) and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 12:19
S16 7	20	(demos denmos depmos) and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 12:20
S16 8	0	senmos	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 12:20
S16 9	20	semos	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 12:20
S17 0	20	(semos demos denmos depmos) and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 12:32
S17 1	68	(semos demos denmos depmos) and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/09 12:20
S17 2	10	("5416351" | "5559352" | "5870268" | "5898205" | "5918127" | "6066879").PN. OR ("6444511"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 12:26
S17 3	1	10/278094	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 12:27

S17 4	16	(two dual double) near (semos demos denmos depmos)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/09 12:35
S17 5	0	parallel near (semos denmos depmos)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 12:35
S17 6	9	parallel with (semos denmos depmos)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 12:36
S17 7	7	second with (semos denmos depmos)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 13:26
S17 8	199	second with (semos denmos depmos drain adj extend$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 13:27
S17 9	21	dual with (semos denmos depmos drain adj extend$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/09 13:27
S18 0	33	("5276371" | "5374565" | "5438213" | "5455436" | "5508548" | "5515226" | "5548134" | "5576570" | "5674761" | "5707886" | "5897348" | "5953606" | "5994176" | "5998245" | "6004838" | "6022769").PN. OR ("6143594"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 13:31
S18 1	25	("5516717" | "5529941" | "5554544" | "5585299" | "5618740" | "5672527" | "5877048" | "5897348" | "5905284" | "5910672" | "5917218" | "5920774").PN. OR ("5994176").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 13:42
S18 2	423645	dual gate and scr	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 13:43

S18 3	28	dual adj gate and scr	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:01
S18 4	1	"5,455,436".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:01
S18 5	35	("5182220" | "5225702").PN. OR ("5455436").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:04
S18 6	14	("20020053704" | "5455436" | "5572394" | "5637900" | "5753381" | "5754380" | "5754381" | "5811856" | "5872379" | "5898205" | "6066879").PN. OR ("6661060"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:07
S18 7	21	("5400202" | "5465189" | "5576557" | "5745323" | "5754380" | "5754381" | "5869873" | "5898205").PN. OR ("6066879"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:19
S18 8	1	"5,753,380".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:20
S18 9	1	"5,753,381".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:24
S19 0	26	ker.in. and beta	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:29
S19 1	76	(lee wu).in. and beta and scr	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:30
S19 2	3	(lee wu).in. and beta same double and scr	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:30
S19 3	1652	(lee wu).in. and beta and silicon	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:30
S19 4	31	(lee wu).in. and beta and silicon adj controlled	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:43
S19 5	1	"6143594".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:45
S19 6	1	"5,455,436".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:47
S19 7	0	denmos same speed	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:48

S198	2	denmos same turn$1on	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 14:53
S199	1	denmos same fast	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 16:39
S200	18	"5473169"	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 16:39
S201	1	"5473169".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 17:16
S202	1	"6066879".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/09 17:16